

**SMALL SIGNAL COMPLEMENTARY PRE-BIASED DUAL TRANSISTOR**
**Features**

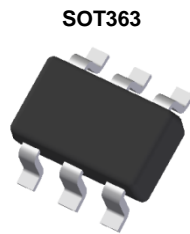
- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Surface Mount Package Suited for Automated Assembly
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony-Free. “Green” Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. <https://www.diodes.com/quality/product-definitions/>**

**Mechanical Data**

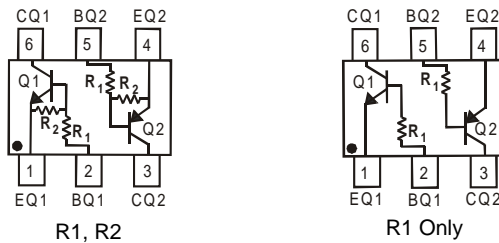
- Package: SOT363
- Package Material: Molded Plastic, “Green” Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.006 grams (Approximate)

Part Number	R1(NOM)	R2(NOM)
DCX124EU	22kΩ	22kΩ
DCX144EU	47kΩ	47kΩ
DCX114YU	10kΩ	47kΩ
DCX123JU	2.2kΩ	47kΩ
DCX114EU	10kΩ	10kΩ
DCX143EU	4.7kΩ	4.7kΩ
DCX143ZU	4.7kΩ	47kΩ
DCX115EU	100kΩ	100kΩ

Part Number	R1 Only
DCX143TU	4.7kΩ
DCX114TU	10kΩ



Top View



R1, R2

Device Schematic

R1 Only

**Ordering Information** (Notes 4, 5)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DCX124EU-7-F	Active	Standard	C17	7	8	3,000
DCX124EUQ-7-F	NRND (Use ACX124EUQ)	Automotive	C17	7	8	3,000
DCX124EUQ-13-F	NRND (Use ACX124EUQ)	Automotive	C17	13	8	10,000
DCX124EUQ-13R-F	NRND (Use ACX124EUQ)	Automotive	C17	13	8	10,000
DCX144EU-7-F	Active	Standard	C20	7	8	3,000
DCX144EU-7R-F	Active	Standard	C20	7	8	3,000
DCX144EUQ-7-F	Active	Automotive	C20	7	8	3,000
DCX144EUQ-7R-F	Active	Automotive	C20	7	8	3,000
DCX114YU-7-F	Active	Standard	C14	7	8	3,000
DCX114YU-7R-F	Active	Standard	C14	7	8	3,000
DCX114YUQ-7-F	NRND (Use ACX114YUQ)	Automotive	C14	7	8	3,000
DCX114YUQ-13-F	NRND (Use ACX114YUQ)	Automotive	C14	13	8	10,000
DCX114YUQ-13R-F	NRND (Use ACX114YUQ)	Automotive	C14	13	8	10,000
DCX123JU-7-F	Active	Standard	C06	7	8	3,000
DCX123JUQ-7-F	Active	Automotive	C06	7	8	3,000
DCX114EU-7-F	Active	Standard	C13	7	8	3,000
DCX114EU-13R-F	Active	Standard	C13	13	8	10,000

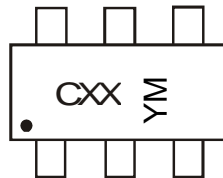
### Ordering Information (Notes 4, 5) (continued)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DCX114EUQ-7-F	NRND (Use ACX114EUQ)	Automotive	C13	7	8	3,000
DCX114EUQ-13-F	NRND (Use ACX114EUQ)	Automotive	C13	13	8	10,000
DCX114EUQ-13R-F	NRND (Use ACX114EUQ)	Automotive	C13	13	8	10,000
DCX143TU-7-F	Active	Standard	C07	7	8	3,000
DCX143EU-7-F	Active	Standard	C08	7	8	3,000
DCX114TU-7-F	Active	Standard	C12	7	8	3,000
DCX143ZU-7-F	Active	Standard	C02	7	8	3,000
DCX115EU-7-F	Active	Standard	C01	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.
  5. NRND = Not Recommended for New Design.

### Marking Information

SOT363



CXX = Product Type Marking Code  
 YM = Date Code Marking  
 Y or  $\bar{Y}$  = Year (ex: I = 2021)  
 M = Month (ex: D = December)

Date Code Key

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	H	I	J	K	L	M	N	O	P	R	S	T
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

**Absolute Maximum Ratings NPN Section** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage <Pin: (6) to (1)>		$V_{CC}$	50	V
Input Voltage <Pin: (2) to (1)>	DCX124EU	$V_{IN}$	-10 to +40	V
	DCX144EU		-10 to +40	
	DCX114YU		-6 to +40	
	DCX123JU		-5 to +12	
	DCX114EU		-10 to +40	
	DCX143TU		-5V Max	
	DCX143EU		-10 to +30	
	DCX114TU		-5V Max	
Output Current	DCX143ZU	$I_O$	-10 to +30	mA
	DCX115EU		-10 to +40	
	DCX124EU		30	
	DCX144EU		30	
	DCX114YU		70	
	DCX123JU		100	
	DCX114EU		50	
	DCX143TU		100	
Output Current	DCX143EU	$I_C$ (Max)	100	mA
	DCX114TU		100	
	DCX143ZU		100	
	DCX115EU		20	

**Absolute Maximum Ratings PNP Section** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage <Pin: (4) to (3)>		$V_{CC}$	50	V
Input Voltage <Pin: (5) to (4)>	DCX124EU	$V_{IN}$	+10 to -40	V
	DCX144EU		+10 to -40	
	DCX114YU		+6 to -40	
	DCX123JU		+5 to -12	
	DCX114EU		+10 to -40	
	DCX143TU		+5V Max	
	DCX143EU		+10 to -30	
	DCX114TU		+5V Max	
Output Current	DCX143ZU	$I_O$	+5 to -30	mA
	DCX115EU		+10 to -40	
	DCX124EU		-30	
	DCX144EU		-30	
	DCX114YU		-70	
	DCX123JU		-100	
	DCX114EU		-50	
	DCX143TU		-100	
Output Current	DCX143EU	$I_C$ (Max)	-100	mA
	DCX114TU		-100	
	DCX143ZU		-100	
	DCX115EU		-20	

**Thermal Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6, 7)	$P_D$	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	625	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

Notes: 6. Mounted on FR-4 PC Board with minimum recommended pad layout.  
7. 150mW per element must not be exceeded.

**Thermal Characteristics** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

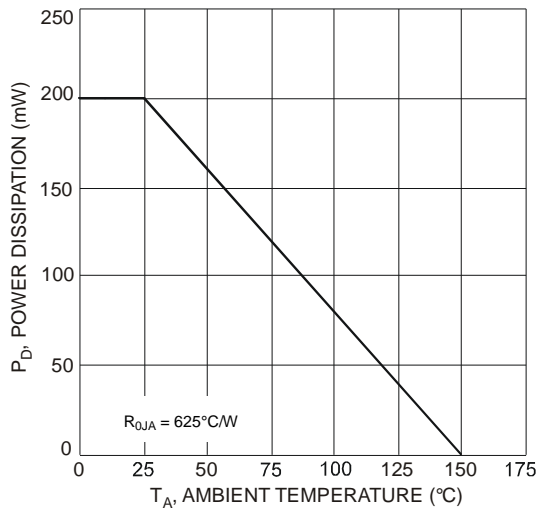


Fig. 1 Power Derating Curve

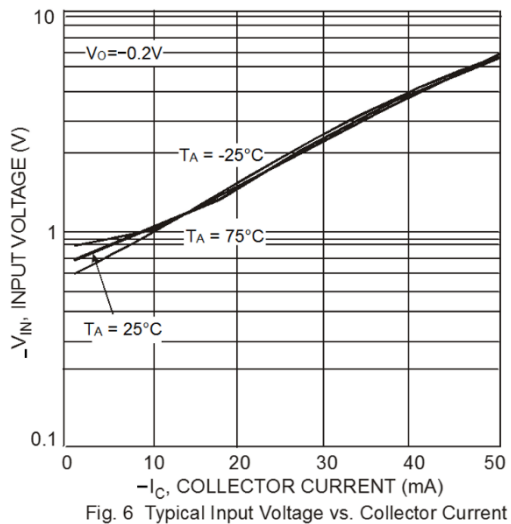
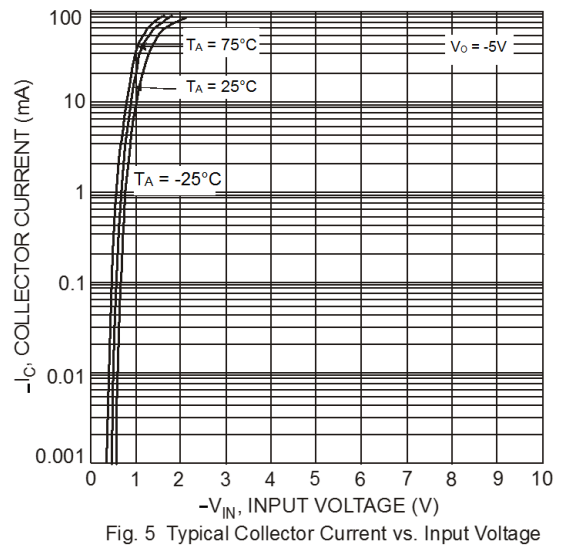
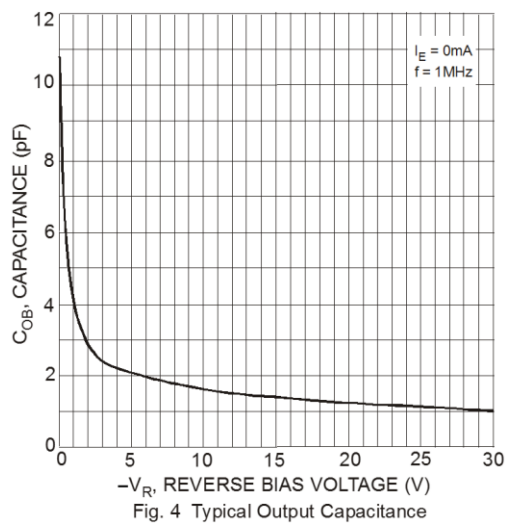
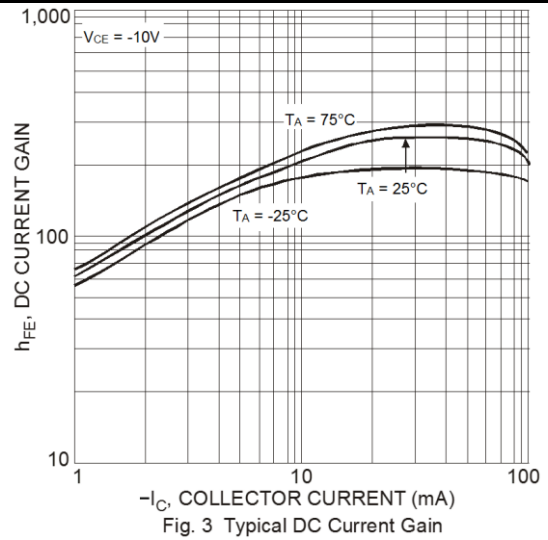
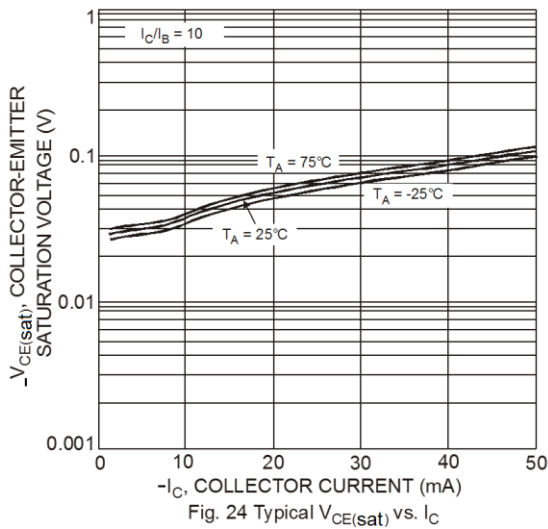
**Electrical Characteristics NPN Section** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition	
<b>R1 Only (DCX143TU &amp; DCX114TU)</b>								
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	50	—	—	V	I <sub>C</sub> = 50μA	
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	50	—	—	V	I <sub>C</sub> = 1mA	
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	5	—	—	V	I <sub>E</sub> = 50μA	
Collector Cutoff Current		I <sub>CBO</sub>	—	—	0.5	μA	V <sub>CB</sub> = 50V	
Emitter Cutoff Current		I <sub>EBO</sub>	—	—	0.5	μA	V <sub>EB</sub> = 4V	
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	—	—	0.3	V	I <sub>C</sub> /I <sub>B</sub> = 2.5mA / 0.25mA DCX143TU I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA DCX114TU	
DC Current Transfer Ratio		h <sub>FE</sub>	100	250	600	—	I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V	
Input Resistor (R <sub>1</sub> ) Tolerance		ΔR <sub>1</sub>	-30	—	+30	%	—	
Gain-Bandwidth Product		f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz	
<b>R1/R2 Only</b>								
Input Voltage	DCX124EU	V <sub>I(off)</sub>	0.5	1.1	—	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA	
	DCX144EU		0.5	1.1				
	DCX114YU		0.3	—				
	DCX123JU		0.5	—				
	DCX114EU		0.5	1.1				
	DCX143EU		0.5	1.16				
	DCX143ZU		0.5	—				
	DCX115EU		0.5	—				
	DCX124EU	V <sub>I(on)</sub>	—	1.9	3.0	V	V <sub>O</sub> = 0.3V, I <sub>O</sub> = 5mA	
	DCX144EU		—	1.9	3.0		V <sub>O</sub> = 0.3V, I <sub>O</sub> = 2mA	
	DCX114YU		—	—	1.4		V <sub>O</sub> = 0.3V, I <sub>O</sub> = 1mA	
	DCX123JU		—	—	1.1		V <sub>O</sub> = 0.3V, I <sub>O</sub> = 5mA	
	DCX114EU		—	1.9	3.0		V <sub>O</sub> = 0.3V, I <sub>O</sub> = 10mA	
	DCX143EU		—	1.99	3.0		V <sub>O</sub> = 0.3V, I <sub>O</sub> = 20mA	
	DCX143ZU		—	—	1.3		V <sub>O</sub> = 0.3V, I <sub>O</sub> = 5mA	
	DCX115EU		—	—	3		V <sub>O</sub> = 0.3V, I <sub>O</sub> = 1mA	
Output Voltage	DCX124EU	V <sub>O(on)</sub>	—	0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA	
	DCX144EU						I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA	
	DCX114YU						I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA	
	DCX123JU						I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA	
	DCX114EU						I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA	
	DCX143EU						I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA	
	DCX143ZU						I <sub>O</sub> /I <sub>I</sub> = 5mA / 0.25mA	
	DCX115EU						I <sub>O</sub> /I <sub>I</sub> = 10mA / 0.5mA	
Input Current	DCX124EU	I <sub>I</sub>	—	—	—	mA	V <sub>I</sub> = 5V	
	DCX144EU							0.36
	DCX114YU							0.18
	DCX123JU							0.88
	DCX114EU							3.6
	DCX143EU							0.88
	DCX143ZU							0.88
	DCX115EU							1.8
Output Current	I <sub>O(off)</sub>	—	—	0.5	μA	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V		
DC Current Gain	DCX124EU	G <sub>I</sub>	—	—	—	—	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA	
	DCX124EUQ						56	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
	DCX144EU						60	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
	DCX114YU						68	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
	DCX114YUQ						68	V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA
	DCX123JU						80	V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA
	DCX114EU						80	V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA
	DCX143EU						30	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
	DCX143ZU						50	V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA
	DCX115EU						80	V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA
DCX115EU	82	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA						
Input Resistor (R <sub>1</sub> ) Tolerance	ΔR <sub>1</sub>	-30	—	+30	%	—		
Resistance Ratio Tolerance	ΔR <sub>2</sub> /R <sub>1</sub>	-20	—	+20	%	—		
Gain-Bandwidth Product	f <sub>T</sub>	—	250	—	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz	

**Electrical Characteristics PNP Section** (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
<b>R1 Only (DCX143TU &amp; DCX114TU)</b>							
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-50	—	—	V	I <sub>C</sub> = -50μA
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	-50	—	—	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	-5	—	—	V	I <sub>E</sub> = -50μA
Collector Cutoff Current		I <sub>CBO</sub>	—	—	-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cutoff Current		I <sub>EBO</sub>	—	—	-0.5	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	—	—	-0.3	V	I <sub>C</sub> /I <sub>B</sub> = 2.5mA / 0.25mA DCX143TU I <sub>C</sub> /I <sub>B</sub> = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h <sub>FE</sub>	100	250	600	—	I <sub>C</sub> = -1mA, V <sub>CE</sub> = -5V
Input Resistor (R <sub>1</sub> ) Tolerance		ΔR <sub>1</sub>	-30	—	+30	%	—
Gain-Bandwidth Product		f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz
<b>R1/R2 Only</b>							
Input Voltage	DCX124EU	V <sub>I(off)</sub>	-0.5	-1.1	—	V	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100μA
	DCX144EU		-0.5	-1.1			
	DCX114YU		-0.3	—			
	DCX123JU		-0.5	—			
	DCX114EU		-0.5	-1.1			
	DCX143EU		-0.5	-1.16			
	DCX143ZU		-0.5	—			
	DCX115EU		-0.5	—			
	DCX124EU	V <sub>I(on)</sub>	—	-1.9	-3.0	V	V <sub>O</sub> = -0.3V, I <sub>O</sub> = -5mA
	DCX144EU		—	-1.9	-3.0		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -2mA
	DCX114YU		—	—	-1.4		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -1mA
	DCX123JU		—	—	-1.1		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -5mA
	DCX114EU		—	-1.9	-3.0		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -10mA
	DCX143EU		—	-2.5	-3.0		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -20mA
	DCX143ZU		—	—	-1.3		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -5mA
	DCX115EU		—	—	-3		V <sub>O</sub> = -0.3V, I <sub>O</sub> = -1mA
	Output Voltage		DCX124EU	V <sub>O(on)</sub>	—		-0.1
DCX144EU		—	-0.1		-0.3	I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA	
DCX114YU		—	-0.1		-0.3	I <sub>O</sub> /I <sub>I</sub> = -5mA / -0.25mA	
DCX123JU		—	-0.1		-0.3	I <sub>O</sub> /I <sub>I</sub> = -5mA / -0.25mA	
DCX114EU		—	-0.1		-0.3	I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA	
DCX143EU		—	-0.1		-0.3	I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA	
DCX143ZU		—	-0.1		-0.3	I <sub>O</sub> /I <sub>I</sub> = -5mA / -0.25mA	
DCX115EU	—	-0.1	-0.3	I <sub>O</sub> /I <sub>I</sub> = -10mA / -0.5mA			
Input Current	DCX124EU	I <sub>I</sub>	—	—	-0.36	mA	V <sub>I</sub> = -5V
	DCX144EU		—	—	-0.18		
	DCX114YU		—	—	-0.88		
	DCX123JU		—	—	-3.6		
	DCX114EU		—	—	-0.88		
	DCX143EU		—	—	-0.88		
	DCX143ZU		—	—	-1.8		
DCX115EU	—	—	-0.15				
Output Current		I <sub>O(off)</sub>	—	—	-0.5	μA	V <sub>CC</sub> = -50V, V <sub>I</sub> = 0V
DC Current Gain	DCX124EU	G <sub>I</sub>	56	—	—	—	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA
	DCX124EUQ		60				V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA
	DCX144EU		68				V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA
	DCX114YU		68				V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA
	DCX114YUQ		80				V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA
	DCX123JU		80				V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA
	DCX114EU		30				V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA
	DCX143EU		40				V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA
	DCX143ZU		80				V <sub>O</sub> = -5V, I <sub>O</sub> = -10mA
DCX115EU	82	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA					
Input Resistor (R <sub>1</sub> ) Tolerance		ΔR <sub>1</sub>	-30	—	+30	%	—
Resistance Ratio Tolerance		ΔR <sub>2</sub> /R <sub>1</sub>	-20	—	+20	%	—
Gain-Bandwidth Product		f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz

**Typical Curves – DCX123JU PNP Section (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)**



**Typical Curves – DCX123JU NPN Section (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)**

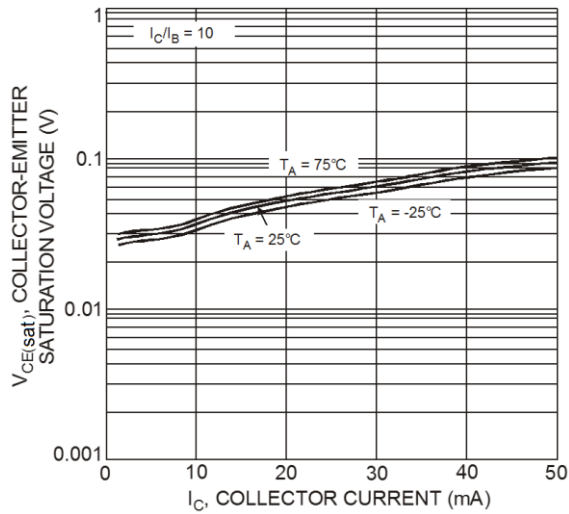


Fig. 7 Typical  $V_{CE(sat)}$  vs.  $I_C$

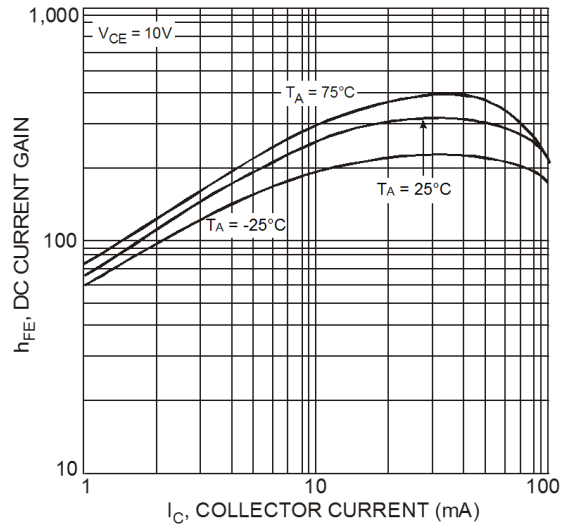


Fig. 8 Typical DC Current Gain

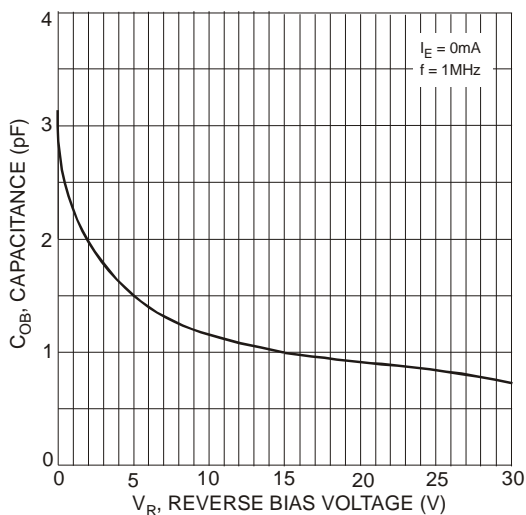


Fig. 9 Typical Output Capacitance

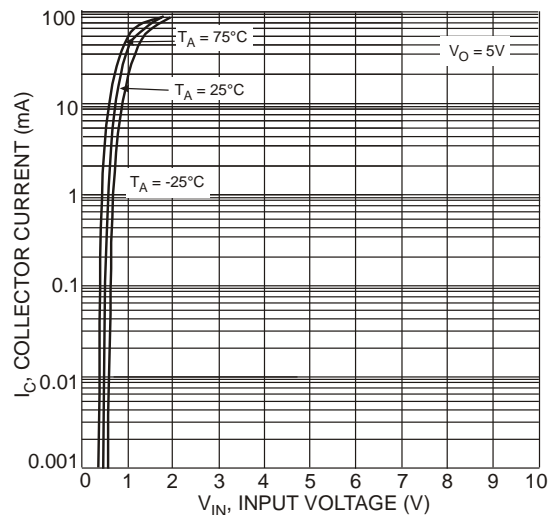


Fig. 10 Typical Collector Current vs. Input Voltage

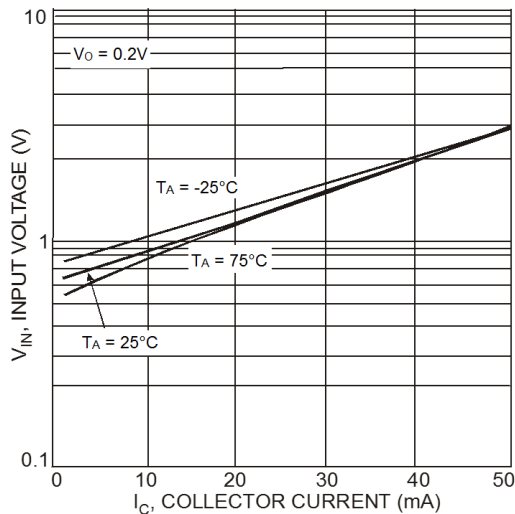


Fig. 11 Typical Input Voltage vs. Collector Current



**Typical Curves – DCX143EU PNP Section** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

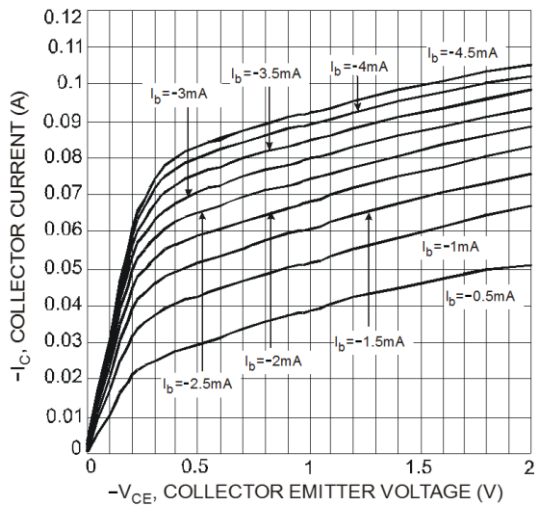


Fig. 12 Typical  $V_{CE}$  vs.  $I_C$

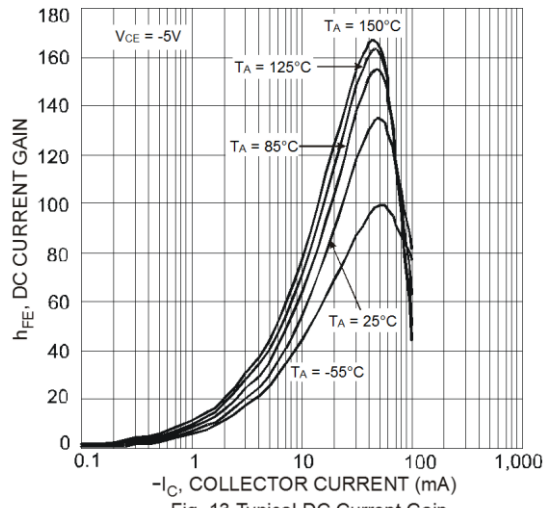


Fig. 13 Typical DC Current Gain

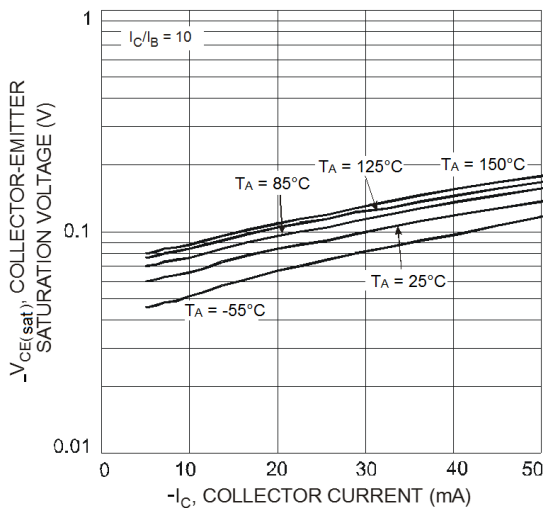


Fig. 14 Typical  $V_{CE(sat)}$  vs.  $I_C$

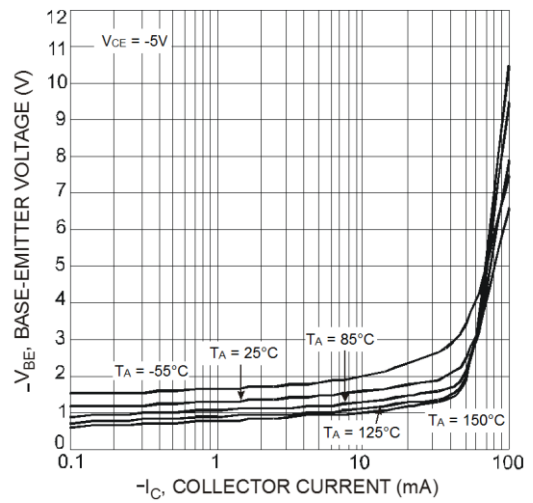


Fig. 15 Typical  $V_{BE}$  vs.  $I_C$

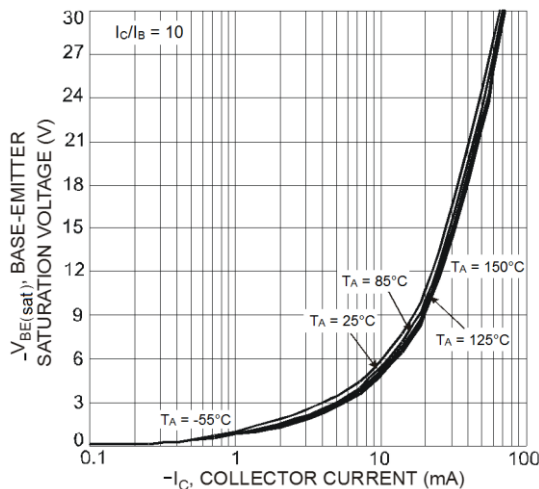


Fig. 16 Typical  $V_{BE(sat)}$  vs.  $I_C$

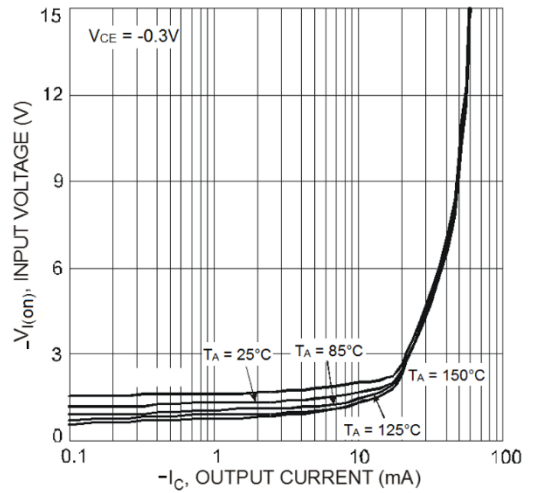


Fig. 17 Typical  $V_{I(on)}$  vs.  $I_C$

**Typical Curves – DCX143EU NPN Section** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

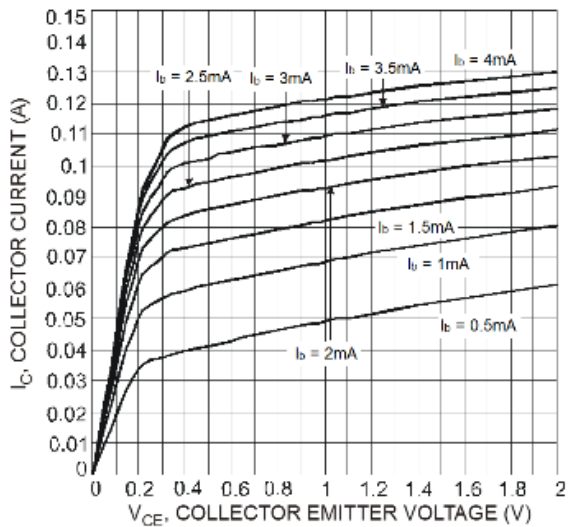


Fig. 18 Typical  $V_{CE}$  vs.  $I_C$

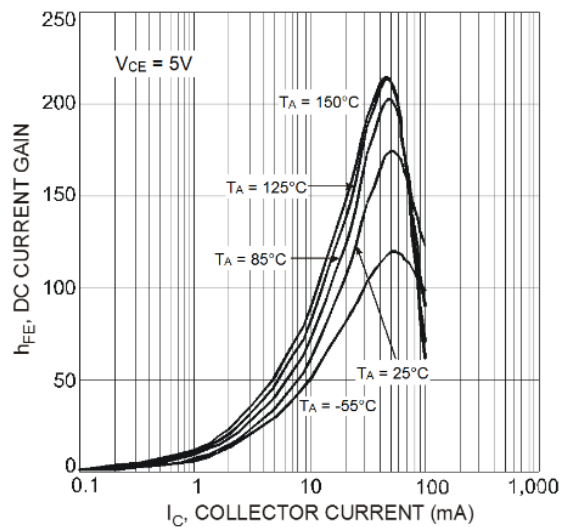


Fig. 19 Typical DC Current Gain

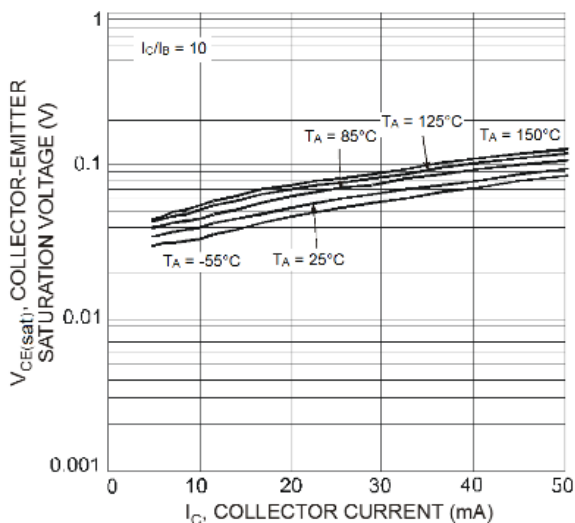


Fig. 20 Typical  $V_{CE(sat)}$  vs.  $I_C$

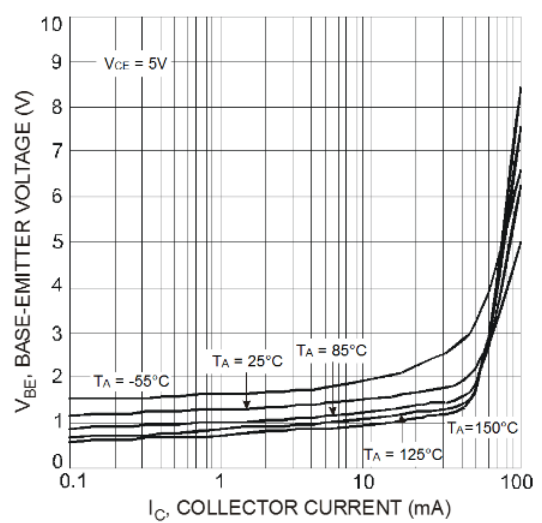


Fig. 21 Typical  $V_{BE}$  vs.  $I_C$

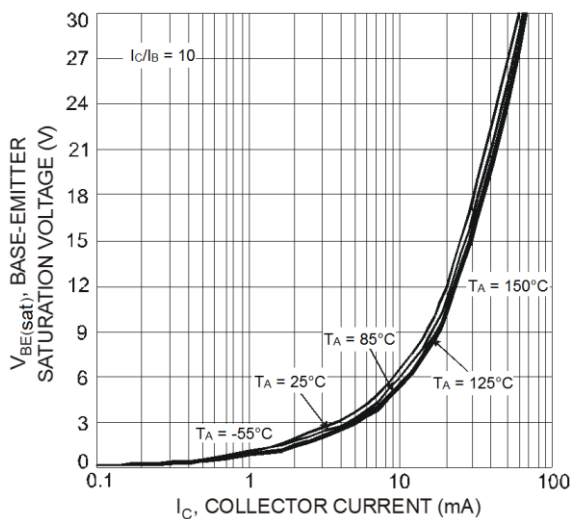


Fig. 22 Typical  $V_{BE(sat)}$  vs.  $I_C$

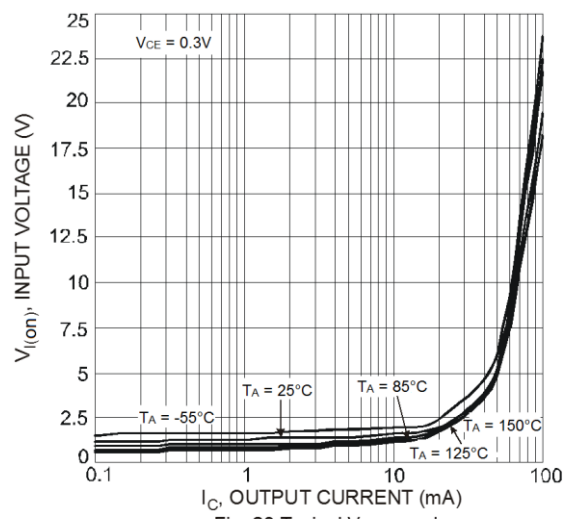


Fig. 23 Typical  $V_{I(on)}$  vs.  $I_C$

**Typical Curves – DCX114TU PNP Section (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)**

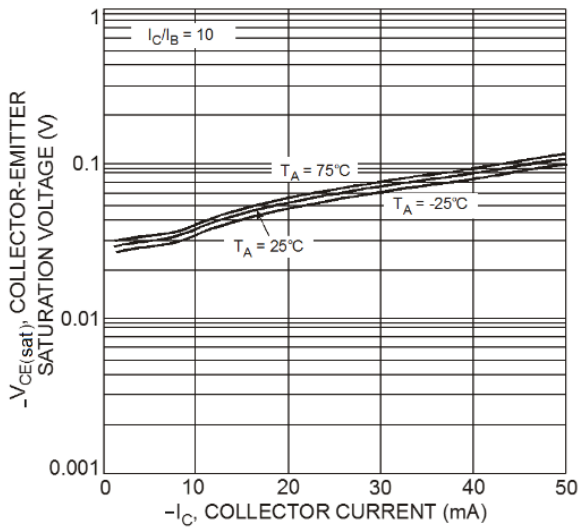


Fig. 24 Typical  $V_{CE(sat)}$  vs.  $I_C$

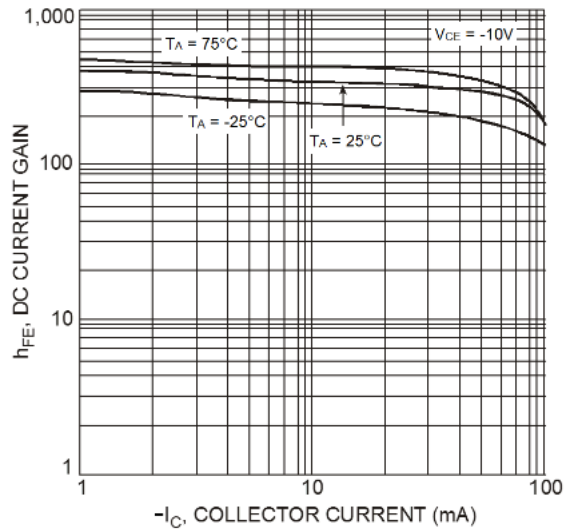


Fig. 25 Typical DC Current Gain

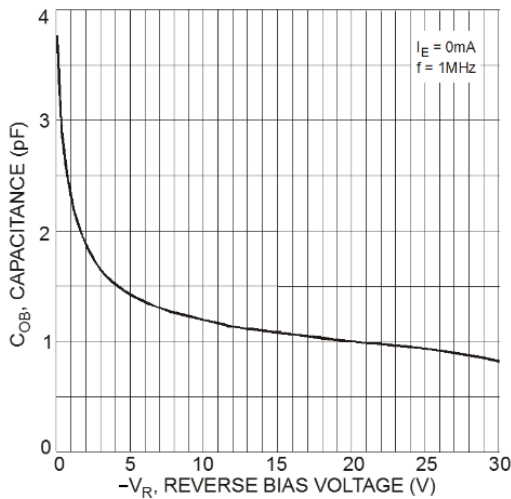


Fig. 26 Typical Output Capacitance

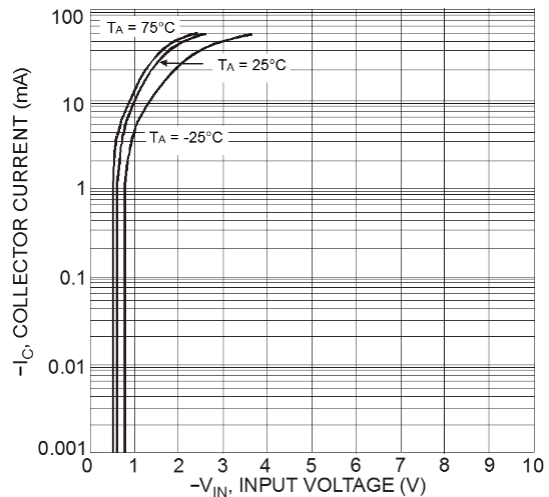


Fig. 27 Typical Collector Current vs. Input Voltage

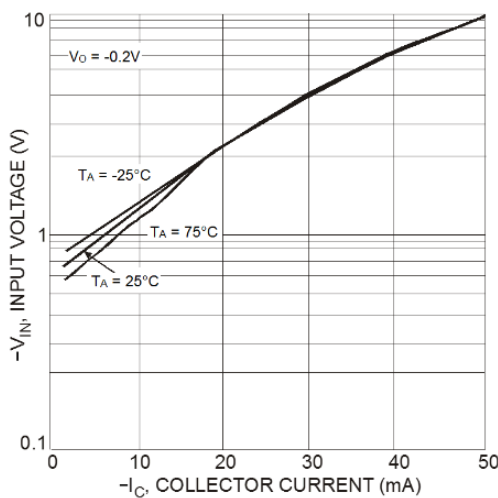


Fig. 28 Typical Input Voltage vs. Collector Current

**Typical Curves – DCX114TU NPN Section** (@  $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

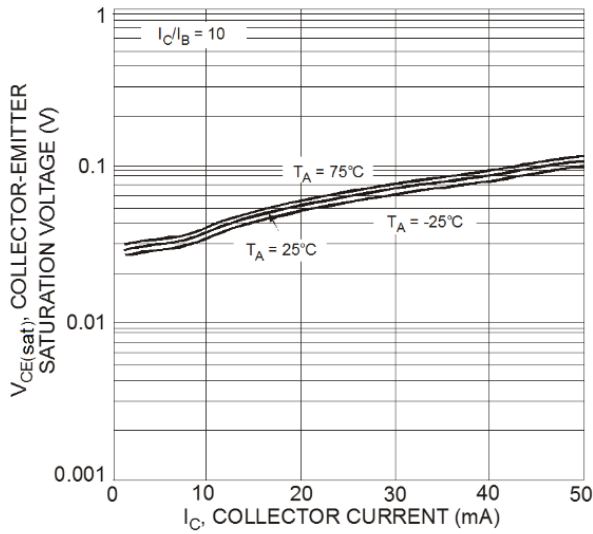


Fig. 29 Typical  $V_{CE(sat)}$  vs.  $I_C$

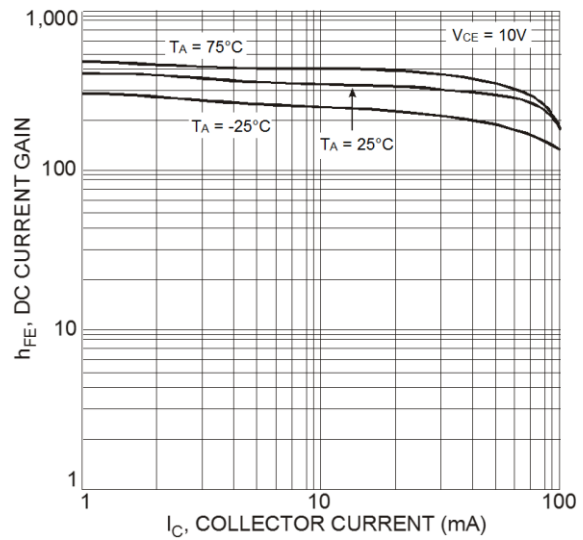


Fig. 30 Typical DC Current Gain

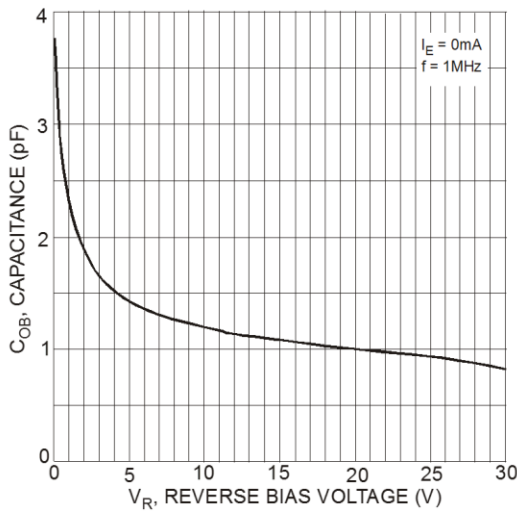


Fig. 31 Typical Output Capacitance

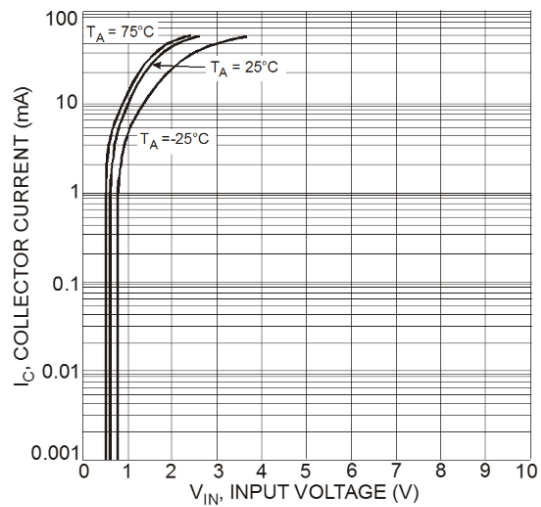


Fig. 32 Typical Collector Current vs. Input Voltage

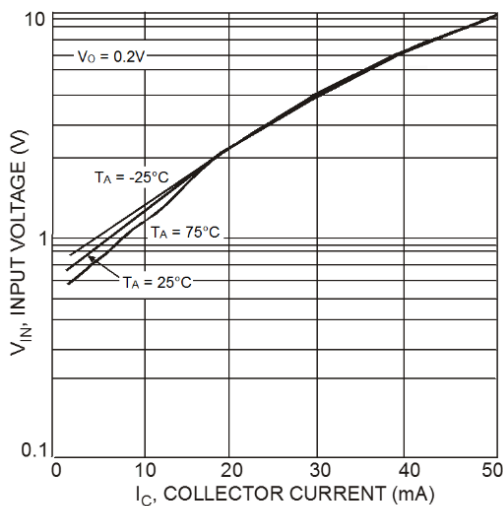
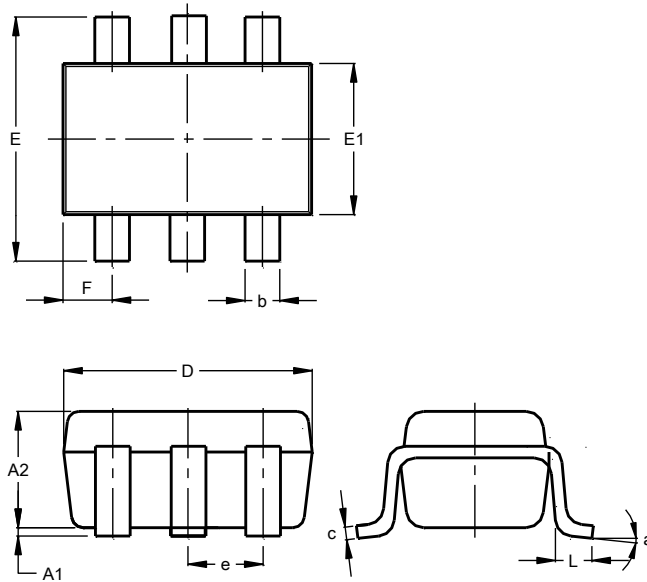


Fig. 33 Typical Input Voltage vs. Collector Current

**Package Outline Dimensions**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT363**

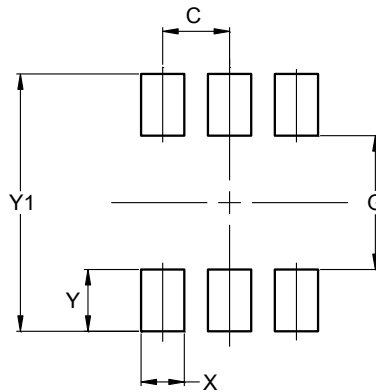


SOT363			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

**SOT363**



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500

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